

# DATA SHEET

## **74HC3G07; 74HCT3G07** **Buffers with open-drain outputs**

Product specification  
File under Integrated Circuits, IC06

2003 Aug 21

## Buffers with open-drain outputs

## 74HC3G07; 74HCT3G07

## FEATURES

- Wide supply voltage range from 2.0 to 6.0 V
- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- ESD protection:  
2000 V Human Body Model (A 114-A)  
200 V Machine Model (A 115-A).
- Balanced propagation delays
- Very small 8 pins package.

## DESCRIPTION

The 74HC3G/HCT3G07 is a high-speed Si-gate CMOS device. Specified in compliance with JEDEC standard no. 7A.

The 74HC3G/HCT3G07 provides three non-inverting buffers.

The outputs of the 74HC3G/HCT3G07 devices are open drains and can be connected to other open-drain outputs to implement active-LOW, wired-OR or active-HIGH wired-AND functions. For digital operation this device must have a pull-up resistor to establish a logic HIGH-level.

## QUICK REFERENCE DATA

GND = 0 V;  $T_{amb} = 25\text{ }^{\circ}\text{C}$ ;  $t_r = t_f \leq 6.0\text{ ns}$ .

| SYMBOL    | PARAMETER                     | CONDITIONS                                     | TYPICAL |       | UNIT |
|-----------|-------------------------------|------------------------------------------------|---------|-------|------|
|           |                               |                                                | HC3G    | HCT3G |      |
| $t_{PZL}$ | propagation delay nA to nY    | $C_L = 50\text{ pF}$ ; $V_{CC} = 4.5\text{ V}$ | 9       | 11    | ns   |
| $t_{PLZ}$ | propagation delay nA to nY    | $C_L = 50\text{ pF}$ ; $V_{CC} = 4.5\text{ V}$ | 11      | 10    | ns   |
| $C_I$     | input capacitance             |                                                | 1.5     | 1.5   | pF   |
| $C_{PD}$  | power dissipation capacitance | notes 1 and 2                                  | 4       | 4     | pF   |

## Notes

1.  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).  
 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:  
 $f_i$  = input frequency in MHz;  $f_o$  = output frequency in MHz;  
 $C_L$  = output load capacitance in pF;  $V_{CC}$  = supply voltage in Volts;  
 $N$  = total switching outputs;  $\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.
2. For HC3G the condition is  $V_I = \text{GND to } V_{CC}$ .  
For HCT3G the condition is  $V_I = \text{GND to } V_{CC} - 1.5\text{ V}$ .

## FUNCTION TABLE

See note 1.

| INPUTS | OUTPUTS |
|--------|---------|
| nA     | nY      |
| L      | L       |
| H      | Z       |

## Note

1. H = HIGH voltage level;  
L = LOW voltage level;  
Z = high-impedance OFF-state.

Buffers with open-drain outputs

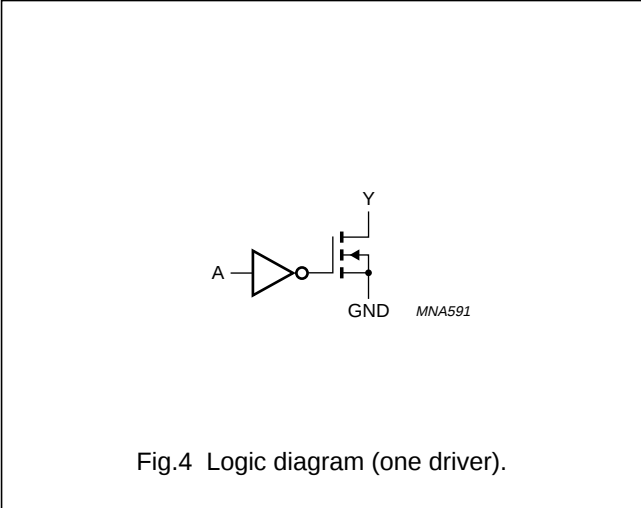
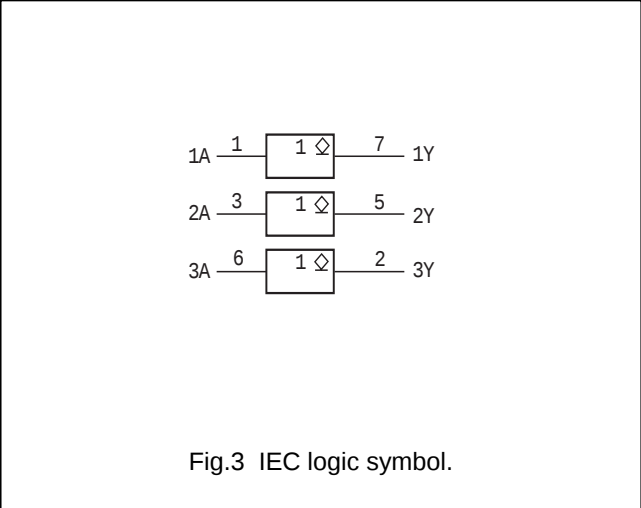
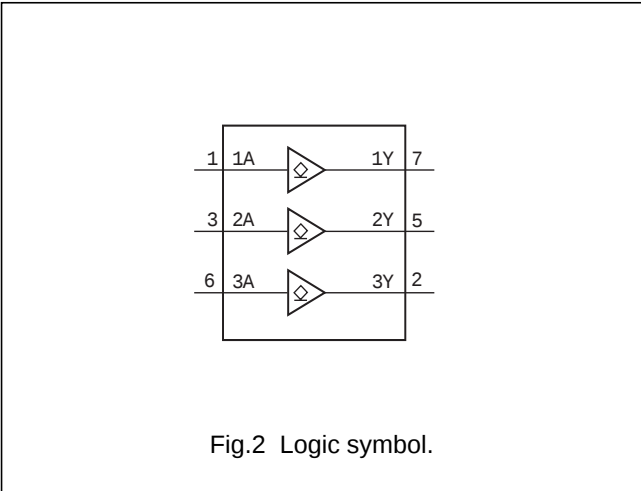
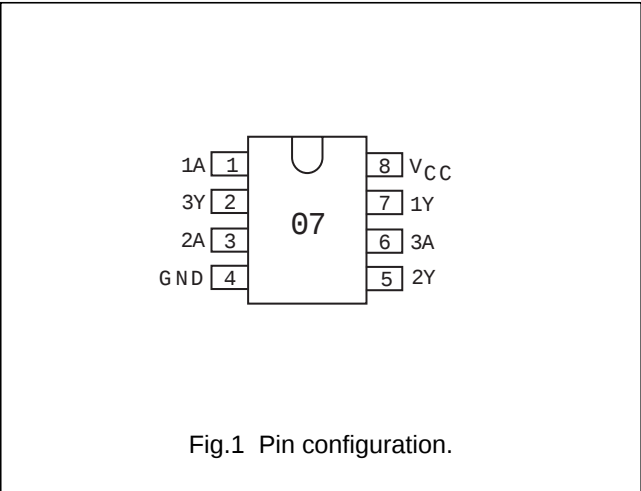
74HC3G07; 74HCT3G07

ORDERING INFORMATION

| TYPE NUMBER | PACKAGES          |      |         |          |          |         |
|-------------|-------------------|------|---------|----------|----------|---------|
|             | TEMPERATURE RANGE | PINS | PACKAGE | MATERIAL | CODE     | MARKING |
| 74HC3G07DP  | −40 to +125 °C    | 8    | TSSOP-8 | plastic  | SOT505-2 | H07     |
| 74HCT3G07DP | −40 to +125 °C    | 8    | TSSOP-8 | plastic  | SOT505-2 | T07     |

PINNING

| PIN     | SYMBOL          | DESCRIPTION       |
|---------|-----------------|-------------------|
| 1, 3, 6 | 1A, 2A, 3A      | data inputs       |
| 2, 5, 7 | 3Y, 2Y, 1Y      | data outputs      |
| 4       | GND             | ground (0 V)      |
| 8       | V <sub>CC</sub> | DC supply voltage |



## Buffers with open-drain outputs

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## RECOMMENDED OPERATING CONDITIONS

| SYMBOL     | PARAMETER                     | CONDITIONS                               | 74HC3G07 |      |          | 74HCT3G07 |      |          | UNIT |
|------------|-------------------------------|------------------------------------------|----------|------|----------|-----------|------|----------|------|
|            |                               |                                          | MIN.     | TYP. | MAX.     | MIN.      | TYP. | MAX.     |      |
| $V_{CC}$   | supply voltage                |                                          | 2.0      | 5.0  | 6.0      | 4.5       | 5.0  | 5.5      | V    |
| $V_I$      | input voltage                 |                                          | 0        | –    | 6.0      | 0         | –    | 5.5      | V    |
| $V_O$      | output voltage                |                                          | 0        | –    | $V_{CC}$ | 0         | –    | $V_{CC}$ | V    |
| $T_{amb}$  | operating ambient temperature | see DC and AC characteristics per device | –40      | +25  | +125     | –40       | +25  | +125     | °C   |
| $t_r, t_f$ | input rise and fall times     | $V_{CC} = 2.0$ V                         | –        | –    | 1000     | –         | –    | –        | ns   |
|            |                               | $V_{CC} = 4.5$ V                         | –        | 6.0  | 500      | –         | 6.0  | 500      | ns   |
|            |                               | $V_{CC} = 6.0$ V                         | –        | –    | 400      | –         | –    | –        | ns   |

## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

| SYMBOL    | PARAMETER                     | CONDITIONS                                        | MIN. | MAX.           | UNIT |
|-----------|-------------------------------|---------------------------------------------------|------|----------------|------|
| $V_{CC}$  | supply voltage                |                                                   | –0.5 | +7.0           | V    |
| $I_{IK}$  | input diode current           | $V_I < -0.5$ V or $V_I > V_{CC} + 0.5$ V; note 1  | –    | ±20            | mA   |
| $I_{OK}$  | output diode current          | $V_O < -0.5$ V; note 1                            | –    | –20            | mA   |
| $V_O$     | output voltage                | active mode; note 1                               | –0.5 | $V_{CC} + 0.5$ | V    |
|           |                               | high-impedance mode; note 1                       | –0.5 | 7.0            | V    |
| $I_O$     | output sink current           | $-0.5$ V < $V_O$ < 7.0 V; note 1                  | –    | –25            | mA   |
| $I_{CC}$  | $V_{CC}$ or GND current       | note 1                                            | –    | 50             | mA   |
| $T_{stg}$ | storage temperature           |                                                   | –65  | +150           | °C   |
| $P_D$     | power dissipation per package | for temperature range from –40 to +125 °C; note 2 | –    | 300            | mW   |

## Notes

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. Above 110 °C the value of  $P_D$  derates linearly with 8 mW/K.

## Buffers with open-drain outputs

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## DC CHARACTERISTICS

## Type 74HC3G07

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| SYMBOL                            | PARAMETER                  | TEST CONDITIONS                                                                                                                                                                         |                     | MIN. | TYP. <sup>(1)</sup> | MAX. | UNIT |
|-----------------------------------|----------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------|------|---------------------|------|------|
|                                   |                            | OTHER                                                                                                                                                                                   | V <sub>CC</sub> (V) |      |                     |      |      |
| T <sub>amb</sub> = –40 to +85 °C  |                            |                                                                                                                                                                                         |                     |      |                     |      |      |
| V <sub>IH</sub>                   | HIGH-level input voltage   |                                                                                                                                                                                         | 2.0                 | 1.5  | 1.2                 | –    | V    |
|                                   |                            |                                                                                                                                                                                         | 4.5                 | 3.15 | 2.4                 | –    | V    |
|                                   |                            |                                                                                                                                                                                         | 6.0                 | 4.2  | 3.2                 | –    | V    |
| V <sub>IL</sub>                   | LOW-level input voltage    |                                                                                                                                                                                         | 2.0                 | –    | 0.8                 | 0.5  | V    |
|                                   |                            |                                                                                                                                                                                         | 4.5                 | –    | 2.1                 | 1.35 | V    |
|                                   |                            |                                                                                                                                                                                         | 6.0                 | –    | 2.8                 | 1.8  | V    |
| V <sub>OL</sub>                   | LOW-level output voltage   | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub><br>I <sub>O</sub> = 20 μA<br>I <sub>O</sub> = 20 μA<br>I <sub>O</sub> = 20 μA<br>I <sub>O</sub> = 4.0 mA<br>I <sub>O</sub> = 5.2 mA | 2.0                 | –    | 0                   | 0.1  | V    |
|                                   |                            |                                                                                                                                                                                         | 4.5                 | –    | 0                   | 0.1  | V    |
|                                   |                            |                                                                                                                                                                                         | 6.0                 | –    | 0                   | 0.1  | V    |
|                                   |                            |                                                                                                                                                                                         | 4.5                 | –    | 0.15                | 0.33 | V    |
|                                   |                            |                                                                                                                                                                                         | 6.0                 | –    | 0.16                | 0.33 | V    |
| I <sub>I</sub>                    | input leakage current      | V <sub>I</sub> = V <sub>CC</sub> or GND                                                                                                                                                 | 6.0                 | –    | –                   | ±1.0 | μA   |
| I <sub>oZ</sub>                   | 3-state output OFF current | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ;<br>V <sub>O</sub> = V <sub>CC</sub> or GND                                                                                        | 6.0                 | –    | –                   | ±5.0 | μA   |
| I <sub>CC</sub>                   | quiescent supply current   | V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0                                                                                                                             | 6.0                 | –    | –                   | 10   | μA   |
| T <sub>amb</sub> = –40 to +125 °C |                            |                                                                                                                                                                                         |                     |      |                     |      |      |
| V <sub>IH</sub>                   | HIGH-level input voltage   |                                                                                                                                                                                         | 2.0                 | 1.5  | –                   | –    | V    |
|                                   |                            |                                                                                                                                                                                         | 4.5                 | 3.15 | –                   | –    | V    |
|                                   |                            |                                                                                                                                                                                         | 6.0                 | 4.2  | –                   | –    | V    |
| V <sub>IL</sub>                   | LOW-level input voltage    |                                                                                                                                                                                         | 2.0                 | –    | –                   | 0.5  | V    |
|                                   |                            |                                                                                                                                                                                         | 4.5                 | –    | –                   | 1.35 | V    |
|                                   |                            |                                                                                                                                                                                         | 6.0                 | –    | –                   | 1.8  | V    |
| V <sub>OL</sub>                   | LOW-level output voltage   | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub><br>I <sub>O</sub> = 20 μA<br>I <sub>O</sub> = 20 μA<br>I <sub>O</sub> = 20 μA<br>I <sub>O</sub> = 4.0 mA<br>I <sub>O</sub> = 5.2 mA | 2.0                 | –    | –                   | 0.1  | V    |
|                                   |                            |                                                                                                                                                                                         | 4.5                 | –    | –                   | 0.1  | V    |
|                                   |                            |                                                                                                                                                                                         | 6.0                 | –    | –                   | 0.1  | V    |
|                                   |                            |                                                                                                                                                                                         | 4.5                 | –    | –                   | 0.4  | V    |
|                                   |                            |                                                                                                                                                                                         | 6.0                 | –    | –                   | 0.4  | V    |
| I <sub>I</sub>                    | input leakage current      | V <sub>I</sub> = V <sub>CC</sub> or GND                                                                                                                                                 | 6.0                 | –    | –                   | ±1.0 | μA   |
| I <sub>oZ</sub>                   | 3-state output OFF current | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ;<br>V <sub>O</sub> = V <sub>CC</sub> or GND                                                                                        | 6.0                 | –    | –                   | ±10  | μA   |
| I <sub>CC</sub>                   | quiescent supply current   | V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0                                                                                                                             | 6.0                 | –    | –                   | 20   | μA   |

## Note

1. All typical values are measured at T<sub>amb</sub> = 25 °C.

## Buffers with open-drain outputs

## 74HC3G07; 74HCT3G07

**Type 74HCT3G07**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| SYMBOL                            | PARAMETER                           | TEST CONDITIONS                                                                                  |                     | MIN. | TYP. <sup>(1)</sup> | MAX. | UNIT |
|-----------------------------------|-------------------------------------|--------------------------------------------------------------------------------------------------|---------------------|------|---------------------|------|------|
|                                   |                                     | OTHER                                                                                            | V <sub>CC</sub> (V) |      |                     |      |      |
| T <sub>amb</sub> = –40 to +85 °C  |                                     |                                                                                                  |                     |      |                     |      |      |
| V <sub>IH</sub>                   | HIGH-level input voltage            |                                                                                                  | 4.5 to 5.5          | 2.0  | 1.6                 | –    | V    |
| V <sub>IL</sub>                   | LOW-level input voltage             |                                                                                                  | 4.5 to 5.5          | –    | 1.2                 | 0.8  | V    |
| V <sub>OL</sub>                   | LOW-level output voltage            | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                              |                     |      |                     |      |      |
|                                   |                                     | I <sub>O</sub> = 20 μA                                                                           | 4.5                 | –    | 0                   | 0.1  | V    |
|                                   |                                     | I <sub>O</sub> = 4.0 mA                                                                          | 4.5                 | –    | 0.15                | 0.33 | V    |
| I <sub>I</sub>                    | input leakage current               | V <sub>I</sub> = V <sub>CC</sub> or GND                                                          | 5.5                 | –    | –                   | ±1.0 | μA   |
| I <sub>OZ</sub>                   | 3-state output OFF current          | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ;<br>V <sub>O</sub> = V <sub>CC</sub> or GND | 5.5                 | –    | –                   | ±5.0 | μA   |
| I <sub>CC</sub>                   | quiescent supply current            | V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0                                      | 5.5                 | –    | –                   | 10   | μA   |
| ΔI <sub>CC</sub>                  | additional supply current per input | V <sub>I</sub> = V <sub>CC</sub> – 2.1 V; I <sub>O</sub> = 0                                     | 4.5 to 5.5          | –    | –                   | 375  | μA   |
| T <sub>amb</sub> = –40 to +125 °C |                                     |                                                                                                  |                     |      |                     |      |      |
| V <sub>IH</sub>                   | HIGH-level input voltage            |                                                                                                  | 4.5 to 5.5          | 2.0  | –                   | –    | V    |
| V <sub>IL</sub>                   | LOW-level input voltage             |                                                                                                  | 4.5 to 5.5          | –    | –                   | 0.8  | V    |
| V <sub>OL</sub>                   | LOW-level output voltage            | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                              |                     |      |                     |      |      |
|                                   |                                     | I <sub>O</sub> = 20 μA                                                                           | 4.5                 | –    | –                   | 0.1  | V    |
|                                   |                                     | I <sub>O</sub> = 4.0 mA                                                                          | 4.5                 | –    | –                   | 0.4  | V    |
| I <sub>I</sub>                    | input leakage current               | V <sub>I</sub> = V <sub>CC</sub> or GND                                                          | 5.5                 | –    | –                   | ±1.0 | μA   |
| I <sub>OZ</sub>                   | 3-state output OFF current          | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ;<br>V <sub>O</sub> = V <sub>CC</sub> or GND | 5.5                 | –    | –                   | ±10  | μA   |
| I <sub>CC</sub>                   | quiescent supply current            | V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0                                      | 5.5                 | –    | –                   | 20   | μA   |
| ΔI <sub>CC</sub>                  | additional supply current per input | V <sub>I</sub> = V <sub>CC</sub> – 2.1 V; I <sub>O</sub> = 0                                     | 4.5 to 5.5          | –    | –                   | 410  | μA   |

**Note**

1. All typical values are measured at T<sub>amb</sub> = 25 °C.

## Buffers with open-drain outputs

## 74HC3G07; 74HCT3G07

## AC CHARACTERISTICS

## Type 74HC3G07

GND = 0 V;  $t_r = t_f \leq 6.0$  ns;  $C_L = 50$  pF.

| SYMBOL           | PARAMETER                     | TEST CONDITIONS  |                     | T <sub>amb</sub> (°C) |                     |      |             |      | UNIT |
|------------------|-------------------------------|------------------|---------------------|-----------------------|---------------------|------|-------------|------|------|
|                  |                               | WAVEFORMS        | V <sub>CC</sub> (V) |                       | –40 to +85          |      | –40 to +125 |      |      |
|                  |                               |                  |                     | MIN.                  | TYP. <sup>(1)</sup> | MAX. | MIN.        | MAX. |      |
| t <sub>PZL</sub> | propagation delay<br>nA to nY | see Figs 5 and 6 | 2.0                 | –                     | 25                  | 95   | –           | 125  | ns   |
|                  |                               |                  | 4.5                 | –                     | 9                   | 19   | –           | 25   | ns   |
|                  |                               |                  | 6.0                 | –                     | 7                   | 16   | –           | 20   | ns   |
| t <sub>PLZ</sub> | propagation delay<br>nA to nY | see Figs 5 and 6 | 2.0                 | –                     | 25                  | 95   | –           | 125  | ns   |
|                  |                               |                  | 4.5                 | –                     | 11                  | 23   | –           | 30   | ns   |
|                  |                               |                  | 6.0                 | –                     | 10                  | 23   | –           | 26   | ns   |
| t <sub>THL</sub> | output transition<br>time     | see Figs 5 and 6 | 2.0                 | –                     | 18                  | 95   | –           | 125  | ns   |
|                  |                               |                  | 4.5                 | –                     | 6                   | 19   | –           | 25   | ns   |
|                  |                               |                  | 6.0                 | –                     | 5                   | 16   | –           | 20   | ns   |

## Note

1. All typical values are measured at T<sub>amb</sub> = 25 °C.

## Type 74HCT3G07

GND = 0 V;  $t_r = t_f \leq 6.0$  ns;  $C_L = 50$  pF.

| SYMBOL           | PARAMETER                     | TEST CONDITIONS  |                     | T <sub>amb</sub> (°C) |                     |      |             |      | UNIT |
|------------------|-------------------------------|------------------|---------------------|-----------------------|---------------------|------|-------------|------|------|
|                  |                               | WAVEFORMS        | V <sub>CC</sub> (V) | –40 to +85            |                     |      | –40 to +125 |      |      |
|                  |                               |                  |                     | MIN.                  | TYP. <sup>(1)</sup> | MAX. | MIN.        | MAX. |      |
| t <sub>PZL</sub> | propagation delay<br>nA to nY | see Figs 5 and 6 | 4.5                 | –                     | 11                  | 27   | –           | 32   | ns   |
| t <sub>PLZ</sub> | propagation delay<br>nA to nY | see Figs 5 and 6 | 4.5                 | –                     | 10                  | 26   | –           | 31   | ns   |
| t <sub>THL</sub> | output transition<br>time     | see Figs 5 and 6 | 4.5                 | –                     | 6                   | 19   | –           | 22   | ns   |

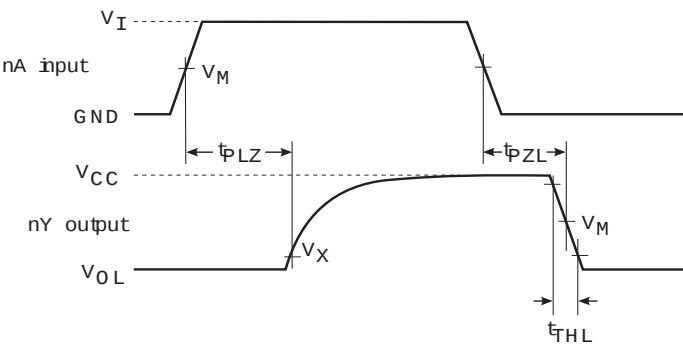
## Note

1. All typical values are measured at T<sub>amb</sub> = 25 °C.

Buffers with open-drain outputs

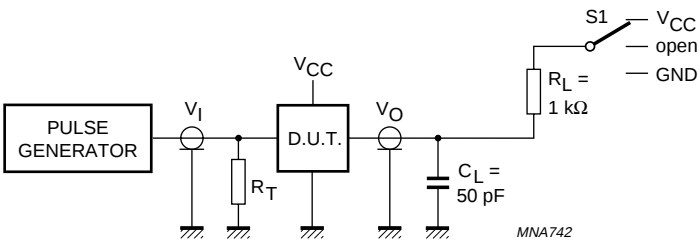
74HC3G07; 74HCT3G07

AC WAVEFORMS



For HC3G:  $V_M = 50\%$ ;  $V_I = \text{GND to } V_{CC}$ .  
For HCT3G:  $V_M = 1.3 \text{ V}$ ;  $V_I = \text{GND to } 3.0 \text{ V}$ .  
For HC3G and HCT3G:  $V_X = 0.1 \times V_{CC}$ .

Fig.5 The input (nA) to output (nY) propagation delays and transition times.



| TEST                               | S <sub>1</sub>  |
|------------------------------------|-----------------|
| t <sub>PLH</sub> /t <sub>PHL</sub> | open            |
| t <sub>PLZ</sub> /t <sub>PZL</sub> | V <sub>CC</sub> |
| t <sub>PHZ</sub> /t <sub>PZH</sub> | GND             |

Definitions for test circuit:  
 $C_L$  = load capacitance including jig and probe capacitance (see “AC characteristics”).  
 $R_T$  = termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

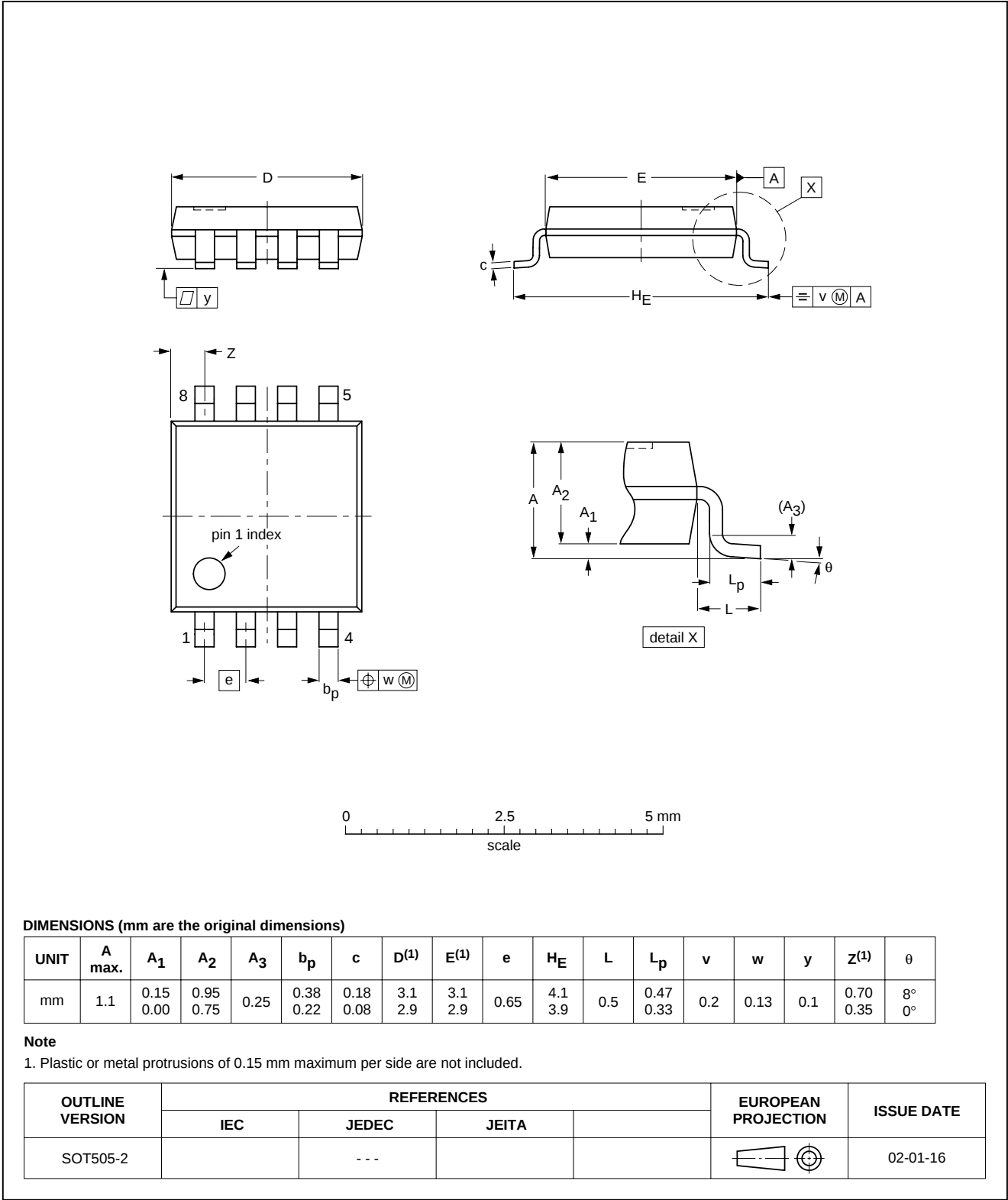
Fig.6 Load circuitry for switching times.

Buffers with open-drain outputs

74HC3G07; 74HCT3G07

PACKAGE OUTLINE

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm    SOT505-2



## Buffers with open-drain outputs

74HC3G07; 74HCT3G07

## DATA SHEET STATUS

| DATA SHEET STATUS         | PRODUCT STATUS | DEFINITIONS <sup>(1)</sup>                                                                                                                                                                                                                                 |
|---------------------------|----------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Objective specification   | Development    | This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.                                                                                                          |
| Preliminary specification | Qualification  | This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product. |
| Product specification     | Production     | This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.                                                       |

## Note

1. Please consult the most recently issued data sheet before initiating or completing a design.

## DEFINITIONS

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

**Limiting values definition** — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

**Application information** — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

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